### **DRIVER**

# DR-AN-10-MO

# 10 GHz Analog Driver

The DR-AN-10-MO is a wideband RF amplifier module designed for analog applications at frequencies up to 12 GHz.

The DR-AN-10-MO is characterized by a low Noise Figure and a linear transfer function whose 1 dB compression point is above 21 dBm. It exhibits flat Group Delay and Gain curves with reduced ripple over the entire bandwidth.

The DR-AN-10-MO comes in a compact 52 mm  $\times$  25.6 mm housing with K type RF connectors (compatible SMA) and with an optional heat-sink. It operates from a single power supply for safety and ease of use, and offers gain control over 3 dB.

This amplifier module is ideally suited to drive optical modulators for analog applications.



#### **Features**

- Output voltage up to 9 V<sub>nn</sub>
- · Linear amplifier
- Flat gain up to 12 GHz
- Single voltage power supply
- · Low group delay variation

#### **Applications**

- LiNbO<sub>3</sub> modulators
- · OFDM, RF over Fiber
- · Linear amplification
- · Clock amplifier
- Research & Development

#### **Options**

Heat-sink

### **Performance Highlights**

n Ty	о Мах	Unit
) k 11 (	G -	Hz
-	9	$V_{pp}$
30	-	dB
-	-	dBm
22	-	dB
-	-15	dBc
-	6	dB
	) k 11 ( - 30	9 30 -  22 - 15

Measurements for  $V_{bias}$  = 12 V,  $V_{amp}$  = 1.2 V,  $I_{bias}$  = 310 mA



# DRIVER | **DR-AN-10-MO** | 2/5

# DR-AN-10-MO

# 10 GHz Analog Driver

### **DC Electrical Characteristics**

Parameter	Symbol	Min	Тур	Max	Unit
Supply voltage (fixed)	$V_{ m bias}$	11	12	13	V
Current consumption	bias	-	300	400	mA
Gain control voltage	$V_{amp}$	-	1.2	1.3	V

### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Lower frequency	f <sub>3db</sub> , lower	-3 dB point	50	-	-	kHz
Upper frequency	f <sub>3db</sub> , upper	-3 dB point	_	11	-	GHz
Gain	S <sub>21</sub>	Small signal, f < 10 GHz	28	30	-	dB
Gain ripple	-	f < 10 GHz	-	-	± 1.5	dB
Input return loss	S <sub>11</sub>	f < 10 GHz	-	-10	-	dB
Output return loss	S <sub>22</sub>	f < 10 GHz	-	-15	-	dB
Isolation	S <sub>12</sub>	f < 10 GHz	_	-60	-	dB
Output power 1 dB	P <sub>1 dB</sub>	2 GHz < f < 10 GHz	21	22	-	dBm
Saturated output power	P <sub>sat</sub>	2 GHz < f < 10 GHz	23	-	-	dBm
Output voltage		Linear	0	-	7	\/
	$V_{out}$	Maximum swing	0	-	9	V <sub>pp</sub>
Noise figure	NF	2 GHz < f < 10 GHz	3	-	6	dB
Harmonics	Harm	@P <sub>1 dB</sub> , f < 5 GHz	-	-	-15	dBc
Power dissipation	Р	Small signal	-	3.6	5.2	W

Conditions: S parameters conditions:  $P_{in}$  -30 dBm,  $T_{amb}$  = 25°C, 50  $\Omega$  system

### **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit	
RF input voltage	$V_{in}$	-	0.6	$V_{pp}$	
Supply voltage	V <sub>bias</sub>	0	13	V	
DC current	l bias	0	400	mA	
Gain control voltage	V <sub>amp</sub>	0	1.5	V	
Power dissipation	P <sub>diss</sub>	-	5.2	W	
Operating temperature	T <sub>op</sub>	0	+40	°C	
Storage temperature	T <sub>st</sub>	-20	+70	°C	

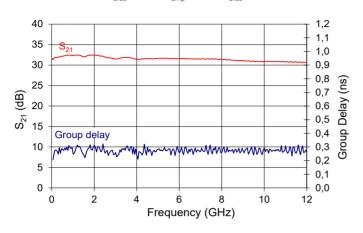


# DRIVER | **DR-AN-10-MO** | 3/5

# DR-AN-10-MO

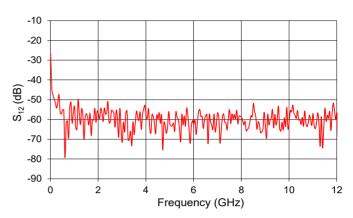
## S<sub>21</sub> and Group Delay Parameter Curves

Conditions:  $V_{bias}$  = 12 V,  $V_{amp}$  = 1.2 V,  $I_{bias}$  = 310 mA



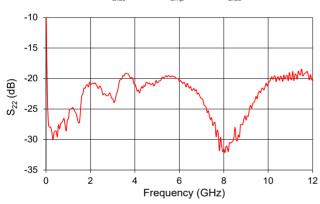
## S<sub>12</sub> Parameter Curve

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 310 \text{ mA}$ 



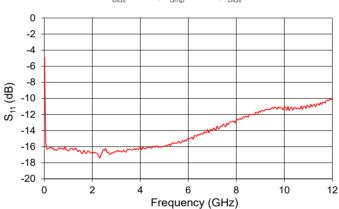
# S<sub>22</sub> Parameter Curve

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 310 \text{ mA}$ 



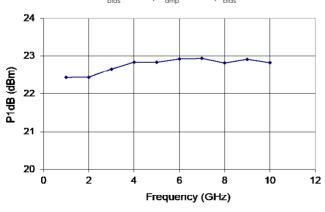
### S<sub>11</sub> Parameter Curve

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 310 \text{ mA}$ 



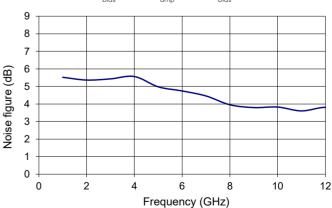
### **Saturated Output Power Curve**

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 310 \text{ mA}$ 



### **Noise Figure Curve**

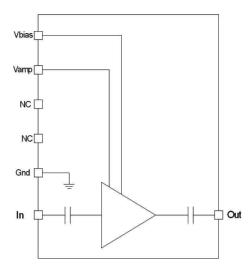
Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 310 \text{ mA}$ 





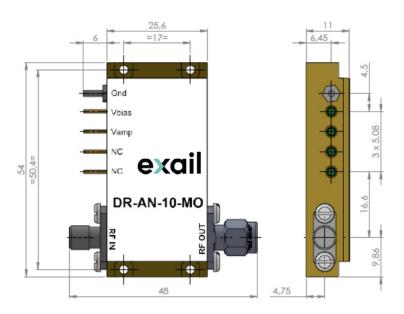
# DRIVER | **DR-AN-10-MO** | 4/5

# **Electrical Schematic Diagram**



# **Mechanical Diagram and Pinout**

All measurements in mm





The heat-sinking of the module is necessary. It's user responsability to use an adequate heat-sink. Refer to page 5 for Exail recommended heat-sink.

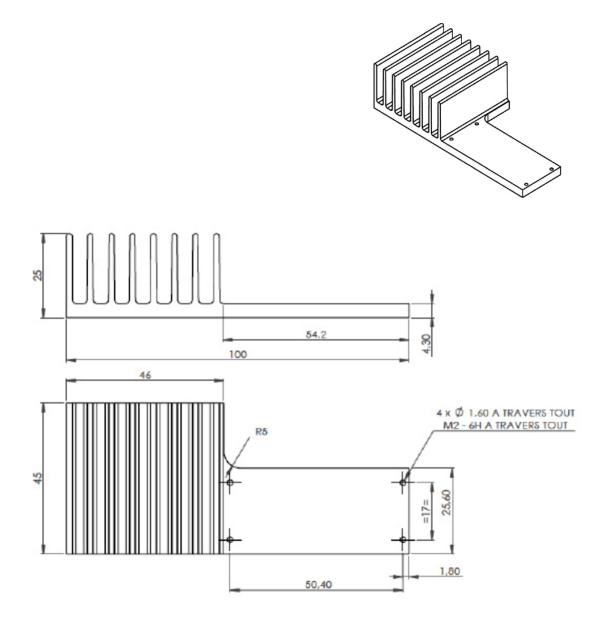
Port	Function	Unit
IN	RF In	Female K connector
OUT	RF Out	Male K connector
V <sub>bias</sub>	Power supply voltage	Set a typical operating specification
V <sub>amp</sub>	Output voltage amplitude adjustment	Adjust for gain control tuning



# DRIVER | **DR-AN-10-MO** | 5/5

### Mechanical Diagram and Pinout with HS-MO2 Heat-sink

All measurements in mm



#### **About us**

Exail Photonics produces specialty optical fibers and Bragg gratings based fiber optics components and provides optical modulation solutions based on the company lithium niobate ( $LiNbO_{\tau}$ ) modulators and RF electronic modules.

Exail Photonics serves a wide range of industries: sensing and instruments, defense, telecommunications, space and fiber lasers as well as research laboratories all over the world.

Exail reserves the right to change, at any time and without notice, the specifications, design, function or form of its products described herein. All statements, specification, technical information related to the products herein are given in good faith and based upon information believed to be reliable and accurate at the moment of printing. However, Exail provides no warranty (whether express or implied or statutory) as to the description, sufficiency, accuracy or completeness, merchantability or fitness for a particular purpose of any information or specification detailed herein. No liability is assumed for any inaccuracies and/or as a result of use of the products. The user must validate all parameters for each application before any use and he shall assume all risks and responsibilities in connection with the use of the products.